## NSN 5961-01-186-8317

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View Online at https://aerobasegroup.com/nsn/5961-01-186-8317 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Overall Height:** 0.210 inches **Overall Width:** 0.250 inches **End Application:** Radar system an/fps-117 **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter reverse voltage, with base short-circuited to emitter and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 6.25 amperes zero-gate-voltage source current minor **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead and 2 flange Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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